

# DATA SHEET

## **TEA5712; TEA5712T** AM/FM stereo DTS radio circuit

Product specification  
Supersedes data of October 1992  
File under Integrated Circuits, IC01

September 1994

**Philips Semiconductors**



**PHILIPS**

## AM/FM stereo DTS radio circuit

## TEA5712; TEA5712T

## FEATURES

- Wide supply voltage range: 1.8 or 2.1 to 12 V
- Low current consumption: 16 mA at AM, 17 mA at FM
- High selectivity with distributed IF gain
- LED driver for stereo indication
- High input sensitivity: 1.6 mV/m (AM), 2.0  $\mu$ V (FM) for 26 dB S/N
- Good strong signal behaviour: 10 V/m at AM, 500 mV at FM
- Low output distortion: 0.8% at AM, 0.3% at FM
- Signal level output
- Soft mute
- Signal dependent stereo
- IF output signals available for IF counting

- Designed for simple and reliable printed-circuit board layout
- High impedance MOSFET input on AM.

## APPLICATIONS

- Portable AM/FM stereo radio
- Mini/midi receiver sets
- Digitally tuned personal headphone radio.

## DESCRIPTION

The TEA5712 is a high performance Bimos IC for use in digitally tuned AM/FM stereo radios. All necessary functions are integrated: from AM and FM front-end to AM detector and FM stereo output stages.

## QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	TYP.
$V_P$	dynamic supply voltage		1.8	–	12	V
$V_P$	static supply voltage		2.1	–	12	V
$I_P$	supply current					
	AM mode		12.8	16.0	20.0	mA
	FM mode		14.3	17.5	21.4	mA
$T_{amb}$	operating ambient temperature		–15	–	+60	$^{\circ}$ C
<b>AM performance</b>						
$V_{in1}$	RF sensitivity		40	55	70	$\mu$ V
$V_{28}$	AF output voltage		36	45	70	mV
THD	total harmonic distortion		–	0.8	2.0	%
<b>FM performance</b>						
$V_{in3}$	RF sensitivity		1.0	2.0	3.8	$\mu$ V
$V_{28}$	AF output voltage		50	61	72	mV
THD	total harmonic distortion		–	0.3	0.8	%
<b>MPX performance</b>						
$\alpha_{cs}$	channel separation		26	30	–	dB
$A_{MPX}$	MPX voltage gain	$V_{AF-L}/V_{in9}$ ; S5 in position MONO	–1.5	0	+1.0	dB
THD	total harmonic distortion		–	0.5	1.0	%

## ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
TEA5712	SDIP32	plastic shrink dual in-line package; 32 leads (400 mil)	SOT232-1
TEA5712T	SO32	plastic small outline package; 32 leads; body width 7.5 mm	SOT287-1

AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

BLOCK DIAGRAM

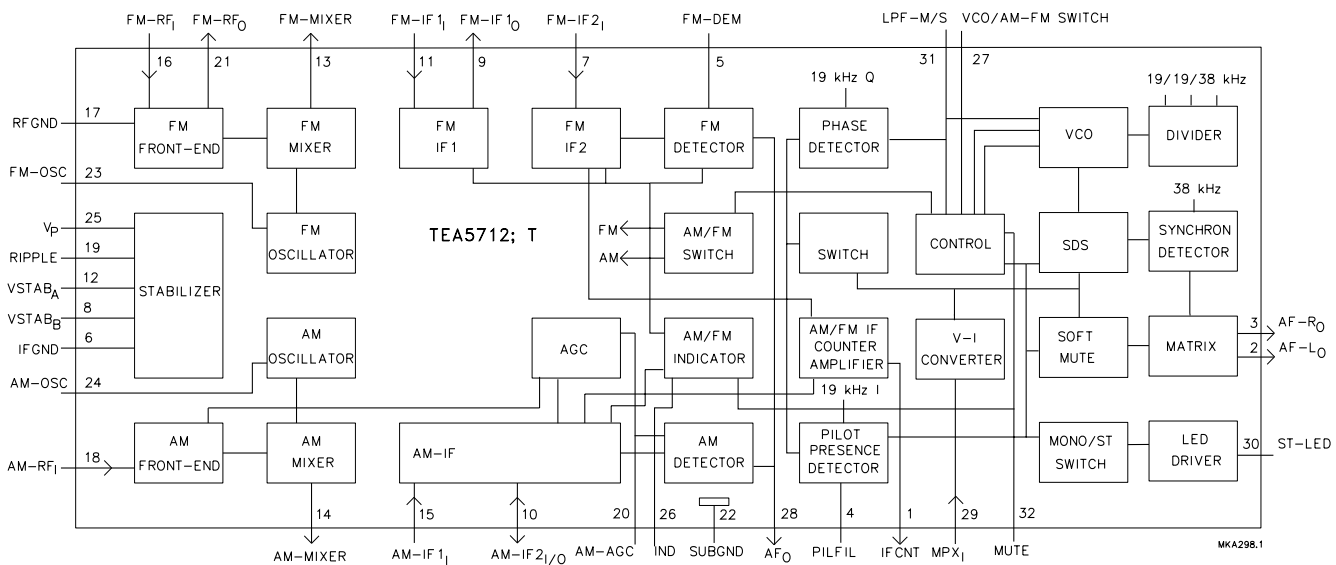


Fig.1 Block diagram.

## AM/FM stereo DTS radio circuit

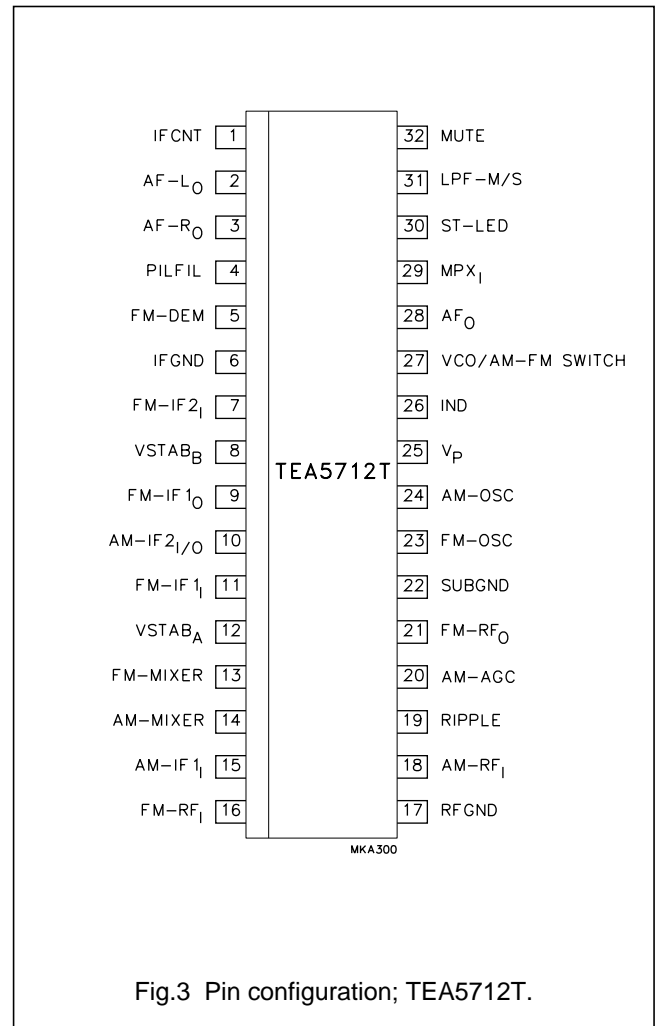
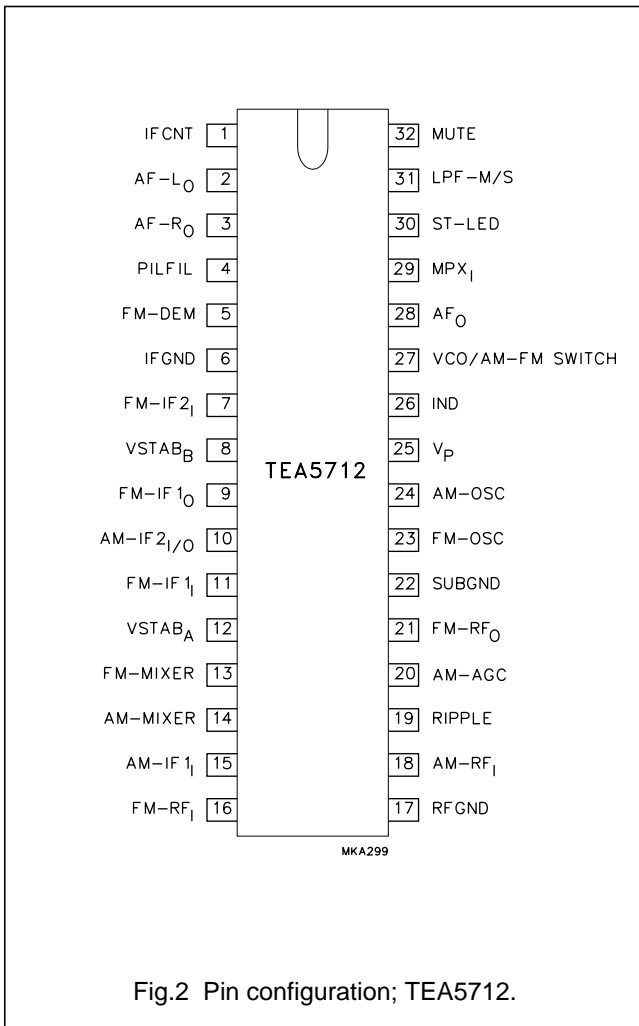
## TEA5712; TEA5712T

## PINNING

SYMBOL	PIN	DESCRIPTION
IFCNT	1	IF signal output for IF counting
AF-L <sub>O</sub>	2	left channel audio output (output impedance typ. 4.3 k $\Omega$ )
AF-R <sub>O</sub>	3	right channel audio output (output impedance typ. 4.3 k $\Omega$ )
PILFIL	4	pilot detector filter pin
FM-DEM	5	ceramic discriminator pin
IFGND	6	ground of IF, detector and MPX stages
FM-IF <sub>2I</sub>	7	second FM-IF input (input impedance typ. 330 $\Omega$ )
VSTAB <sub>B</sub>	8	stabilized internal supply voltage (B)
FM-IF <sub>1O</sub>	9	first FM-IF output (output impedance typ. 330 $\Omega$ )
AM-IF <sub>2I/O</sub>	10	input/output to IFT; output: current source
FM-IF <sub>1I</sub>	11	first FM-IF input (input impedance typ. 330 $\Omega$ )
VSTAB <sub>A</sub>	12	stabilized internal supply voltage (A)
FM-MIXER	13	output to ceramic IF filter (output impedance typ. 330 $\Omega$ )
AM-MIXER	14	open-collector output to IFT
AM-IF <sub>1I</sub>	15	input from IFT or ceramic filter (input impedance typ. 3 k $\Omega$ )
FM-RF <sub>I</sub>	16	FM-RF aerial input (input impedance typ. 50 $\Omega$ )
RFGND	17	FM-RF ground
AM-RF <sub>I</sub>	18	parallel tuned AM aerial circuit to ground (total input capacitance typ. 3 pF)
RIPPLE	19	ripple capacitor pin
AM-AGC	20	AGC capacitor pin
FM-RF <sub>O</sub>	21	parallel tuned FM-RF circuit to ground
SUBGND	22	substrate and RF ground
FM-OSC	23	parallel tuned FM-oscillator circuit to ground
AM-OSC	24	parallel tuned AM-oscillator circuit to ground
V <sub>P</sub>	25	positive supply voltage
IND	26	stop signal output
VCO/AM-FM SWITCH	27	VCO and switch terminal: open for AM; ground for FM
AF <sub>O</sub>	28	AM/FM AF output (output impedance typ. 5 k $\Omega$ )
MPX <sub>I</sub>	29	input for stereo decoder (input impedance typ. 180 k $\Omega$ )
ST-LED	30	stereo indicator
LPF-M/S	31	pin for loop-filter and mono/stereo switch
MUTE	32	mute pin

AM/FM stereo DTS radio circuit

TEA5712; TEA5712T



# AM/FM stereo DTS radio circuit

# TEA5712; TEA5712T

### FUNCTIONAL DESCRIPTION

The AM circuit incorporates a double balanced mixer, a one pin low-voltage oscillator (up to 30 MHz) a field-strength indicator output and is designed for distributed selectivity.

The AM input is designed to be connected to the top of a tuned circuit. AGC controls the IF amplification and for large signals it lowers the input impedance.

The first AM selectivity can be an IFT as well as an IFT combined with a ceramic filter; the second one is an IFT.

The FM circuit incorporates a tuned RF stage, a double balanced mixer, a one-pin oscillator, a field-strength indicator output and is designed for distributed IF ceramic filters. The FM quadrature detector uses a ceramic resonator.

The PLL stereo decoder incorporates a signal dependent stereo circuit, a soft-mute circuit and a stereo indicator LED driver.

### Supply voltage behaviour

The TEA5712 incorporates internal stabilized power supplies. The maximum supply voltage is 12 V, the minimum voltage can go down temporarily to 1.8 V without any loss in performance.

Due to the capacitor at pin 19 (RIPPLE) the IC gives excellent performance, even when the actual supply voltage at pin 25 ( $V_P$ ) drops below the voltage at pin 19 (RIPPLE).

Figures 4, 5 and 6 show that  $V_{stab}$ , which is dominant for the overall IC performance, remains unaffected, even if  $V_P$  drops down to 1.8 V or less. In this typical example the static or average  $V_P$  is equal to 2.5 V. Dips in  $V_{stab}$  appear only when the peak-to-peak value of the AC-component of  $V_P > 2$  V, i.e. when the dynamic value of  $V_P$  drops down to 1.5 V for a short moment.

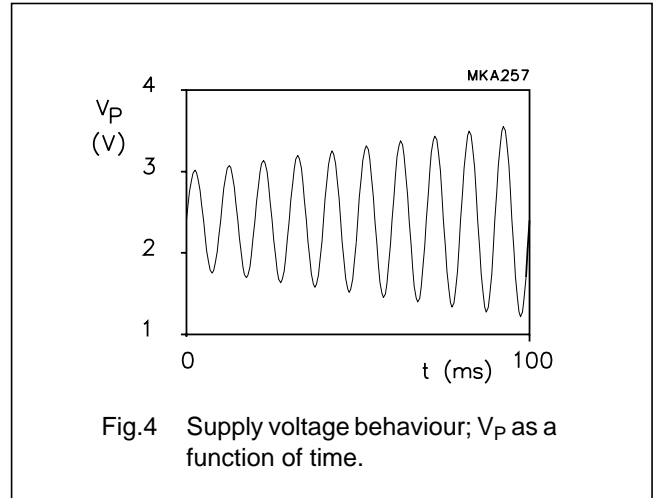


Fig.4 Supply voltage behaviour;  $V_P$  as a function of time.

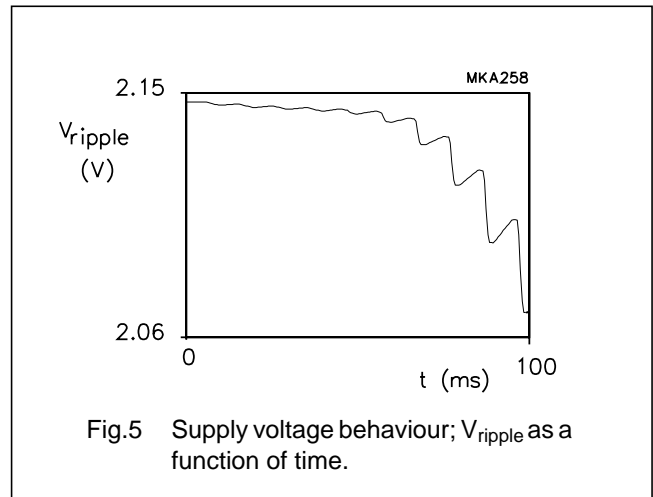


Fig.5 Supply voltage behaviour;  $V_{ripple}$  as a function of time.

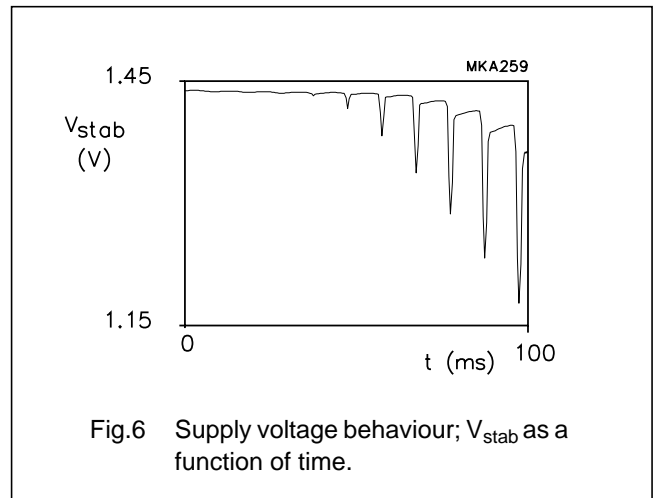


Fig.6 Supply voltage behaviour;  $V_{stab}$  as a function of time.

## AM/FM stereo DTS radio circuit

## TEA5712; TEA5712T

**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
$V_P$	supply voltage	0	12	V
$T_{stg}$	storage temperature	-55	+150	°C
$T_{amb}$	operating ambient temperature	-15	+60	°C
$T_j$	junction temperature	-15	+150	°C

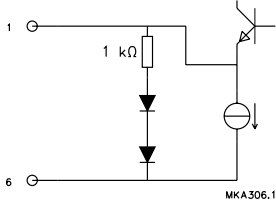
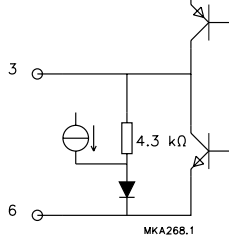
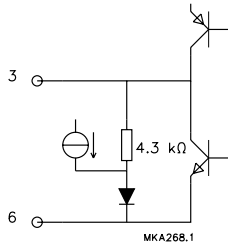
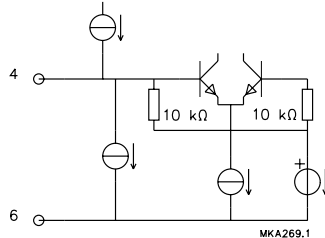
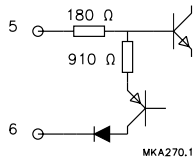
**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient in free air		
	SDIP32	54	K/W
	SO32	68	K/W

AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

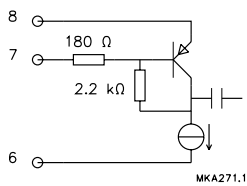
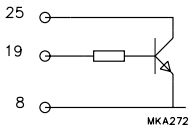
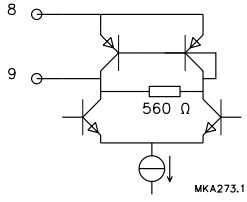
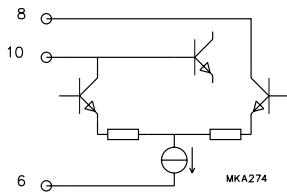
CIRCUIT DESIGN DATA

PIN NO.	PIN SYMBOL	DC PIN VOLTAGE (V)		EQUIVALENT CIRCUIT
		AM	FM	
1	IFCNT output	0.3	0.3	
2	AF-Lo output	0.65	0.65	
3	AF-RO output	0.65	0.65	
4	PILFIL	0.95	0.95	
5	FM-DEM	-	1.0	



AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

PIN NO.	PIN SYMBOL	DC PIN VOLTAGE (V)		EQUIVALENT CIRCUIT
		AM	FM	
6	IFGND	0	0	
7	FM-IF <sub>2I</sub> input	–	0.73	
8	VSTAB <sub>B</sub>	1.4	1.4	
9	FM-IF <sub>1O</sub> output	–	0.69	
10	AM-IF <sub>2I/O</sub> input/output	1.4	1.4	

AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

PIN NO.	PIN SYMBOL	DC PIN VOLTAGE (V)		EQUIVALENT CIRCUIT
		AM	FM	
11	FM-IF <sub>1</sub> input	—	0.73	<p>MKA275.1</p>
12	VSTAB <sub>A</sub>	1.4	1.4	<p>MKA276</p>
13	FM-MIXER output	—	1.0	<p>MKA277.1</p>
14	AM-MIXER output	1.4	1.4	<p>MKA278</p>

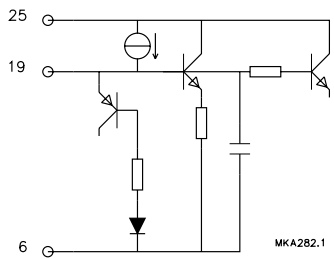
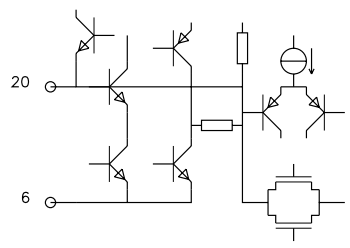
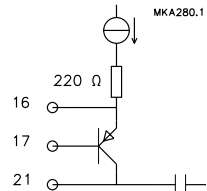
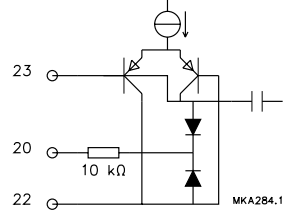
AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

PIN NO.	PIN SYMBOL	DC PIN VOLTAGE (V)		EQUIVALENT CIRCUIT
		AM	FM	
15	AM-IF <sub>1</sub> input	1.4	1.4	
16	FM-RF <sub>1</sub> input	—	0.73	
17	RFGND	0	0	
18	AM-RF <sub>1</sub> input	0	0	

AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

PIN NO.	PIN SYMBOL	DC PIN VOLTAGE (V)		EQUIVALENT CIRCUIT
		AM	FM	
19	RIPPLE	2.1	2.1	
20	AM-AGC	0.1	0.7	
21	FM-RF <sub>O</sub>	0	0	
22	SUBGND	0	0	
23	FM-OSC	0	0	

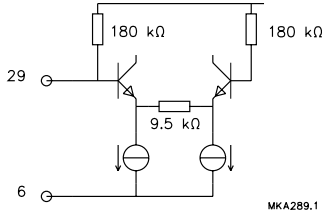
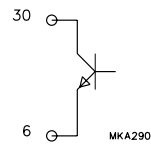
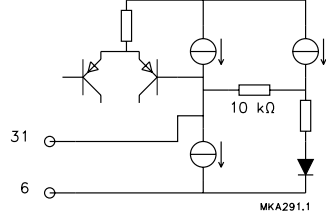
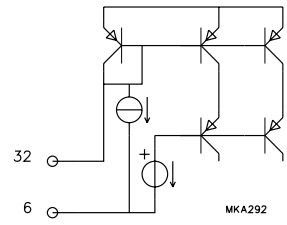
AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

PIN NO.	PIN SYMBOL	DC PIN VOLTAGE (V)		EQUIVALENT CIRCUIT
		AM	FM	
24	AM-OSC	0	0	
25	V <sub>P</sub>	3.0	3.0	
26	IND output	3.0	3.0	
27	VCO and AM/FM switch	1.3	0.95	
28	AF output	0.6	0.7	

AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

PIN NO.	PIN SYMBOL	DC PIN VOLTAGE (V)		EQUIVALENT CIRCUIT
		AM	FM	
29	MPX input	1.23	1.23	
30	ST-LED	3.0	3.0	
31	LPF-M/S	0.1	0.8	
32	MUTE	0.7	0.7	

## AM/FM stereo DTS radio circuit

## TEA5712; TEA5712T

**AM CHARACTERISTICS**

$f_i = 1$  MHz;  $m = 0.3$ ;  $f_m = 1$  kHz;  $V_P = 3.0$  V; measured in Fig.7 with S1 in position B, S2 in position A and S7 in position A; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_P$	supply current	no input signal	12.8	16.0	20.0	mA
$C_i$	input capacitance	$V_{20} = 0.2$ V	–	3	–	pF
$G_c$	front-end conversion gain	$V_{20} = 0.2$ V	1.8	3.3	5.0	
$V_{in1}$	RF sensitivity	S/N = 26 dB	40	55	70	$\mu$ V
$V_{in2}$	IF sensitivity	$V_{28} = 30$ mV; S1 in position A	0.13	0.2	0.45	mV
$V_{28}$	AF output voltage	$V_{in2} = 3.16$ mV; S1 in position A	36	45	70	mV
THD	total harmonic distortion	$V_{in1} = 1$ mV	–	0.8	2.0	%
$V_{in1}$	large signal handling	$m = 0.8$ ; THD $\leq 8\%$	150	300	–	mV
$I_{IND}$	indicator current	$V_{in2} = 100$ mV; S1 in position A	120	170	230	$\mu$ A
$I_{INDOFF}$	indicator OFF current	$V_{in2} = 0$ V; S1 in position A	–	0	10	$\mu$ A
$V_{IFCNTO(p-p)}$	IF count output signal (peak-to-peak value)	$V_{in2} = 10$ V; S4 open	–	400	–	mV
$V_{IFCNT}$	IF count signal	$V_{in10} = 3$ V; S4 closed	–	–70	–	dB

**FM CHARACTERISTICS**

$f_i = 100$  MHz;  $\Delta f = 22.5$  kHz;  $f_m = 1$  kHz;  $V_P = 3.0$  V; measured in Fig.7 with S1 in position B, S2 in position A and S7 in position A; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_P$	supply current	no input signal	14.3	17.5	21.4	mA
$V_{in3}$	RF limiting sensitivity	$V_{28} = -3$ dB	0.4	1.2	3.8	$\mu$ V
$V_{in3}$	RF sensitivity	S/N = 26 dB	1.0	2.0	3.8	$\mu$ V
$V_{11}/V_{in3}$	front-end voltage gain	$V_{in3} \leq 1$ mV; including ceramic filter K1	12	18	22	dB
$V_{in4}$	IF sensitivity	S2 in position B; $V_{28} = -3$ dB	–	20	30	$\mu$ V
$V_{28}$	AF output voltage	$V_{in3} = 1$ mV	50	61	72	mV
THD	total harmonic distortion	$V_{in3} = 1$ mV; $\Delta f = 22.5$ kHz	–	0.3	0.8	%
$V_{in3}$	large signal handling	THD $\leq 5\%$	–	500	–	mV
$I_{IND}$	indicator current	$V_{in4} = 100$ mV; S2 in position B	190	255	320	$\mu$ A
$I_{INDOFF}$	indicator OFF current	$V_{in4} = 0$ V; S2 in position B	–	0	2	$\mu$ A
$V_{IFCNTO(p-p)}$	IF count output signal (peak-to-peak value)	$V_{in4} = 10$ V; S4 open	–	360	–	mV
$V_{IFCNT}$	IF count signal	$V_{in10} = 3$ V; S4 closed	–	–50	–	dB

## AM/FM stereo DTS radio circuit

## TEA5712; TEA5712T

**STEREO DECODER CHARACTERISTICS**

$f_i = 1$  kHz;  $V_{in9(L+R)} = 195$  mV; pilot = 20 mV;  $V_P = 3.0$  V; measured in Fig.7 with S1 in position B, S2 in position A, S6 in position A, S7 in position A and S5 in position STEREO; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$A_{MPX}$	MPX voltage gain $V_{AF-L}/V_{in9}$	S5 in position MONO	-1.5	0	+1.0	dB
THD	total harmonic distortion		-	0.5	1.0	%
(S+N)/N	signal plus noise-to-noise ratio	pilot = 20 mV	-	74	-	dB
$\alpha_{cs}$	channel separation	L = 1; R = 0 or L = 0; R = 1	26	30	-	dB
SC	stereo control	$V_{in3} = 120 \mu V$	-	30	-	dB
		$V_{in3} = 10 \mu V$	-	1	-	dB
$\alpha_{MUTE}$	AF output signal suppression	$V_{in3} \leq 2 \mu V$	-	20	-	dB



AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

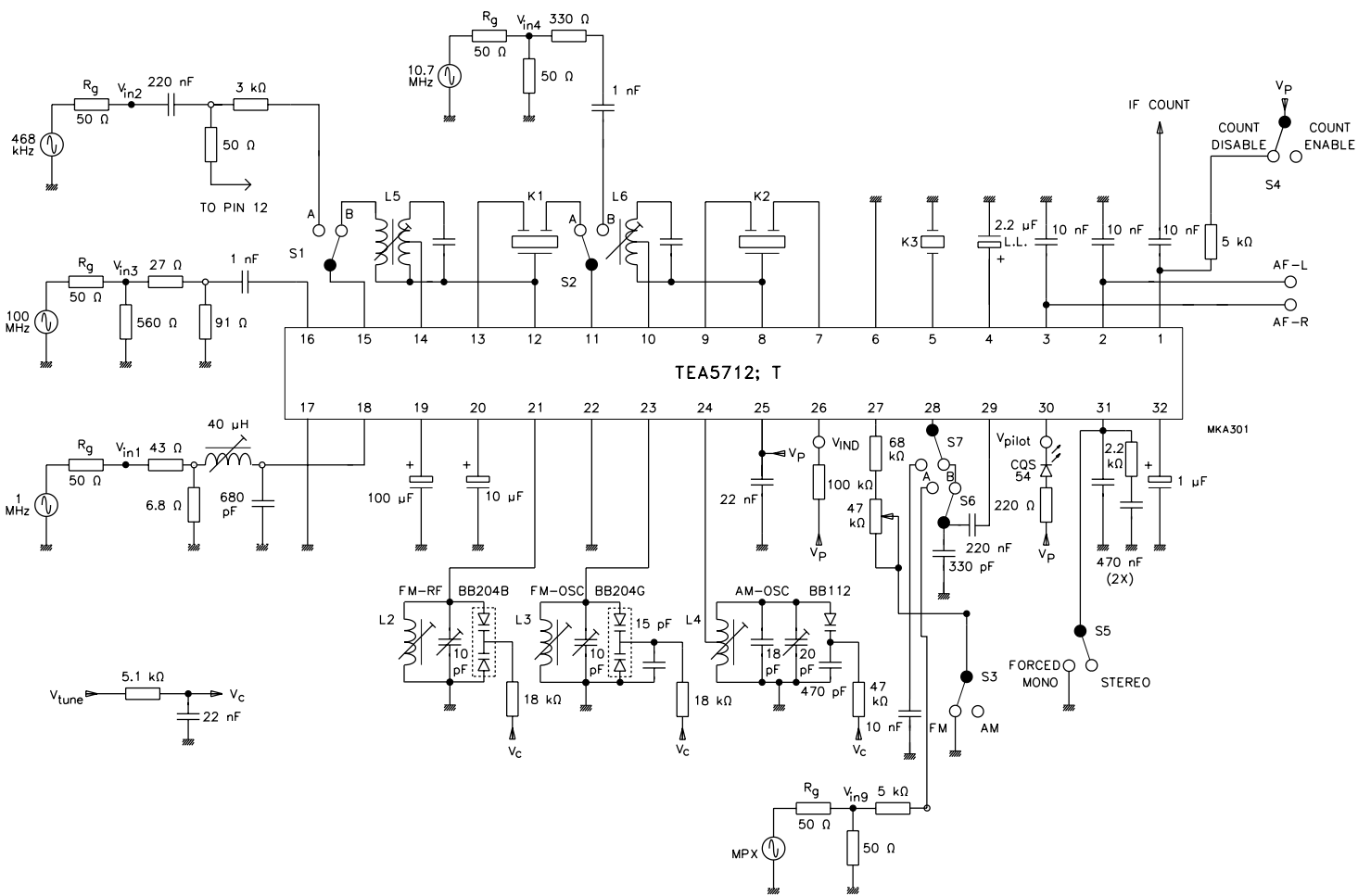


Fig.7 Test circuit.

AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

APPLICATION INFORMATION

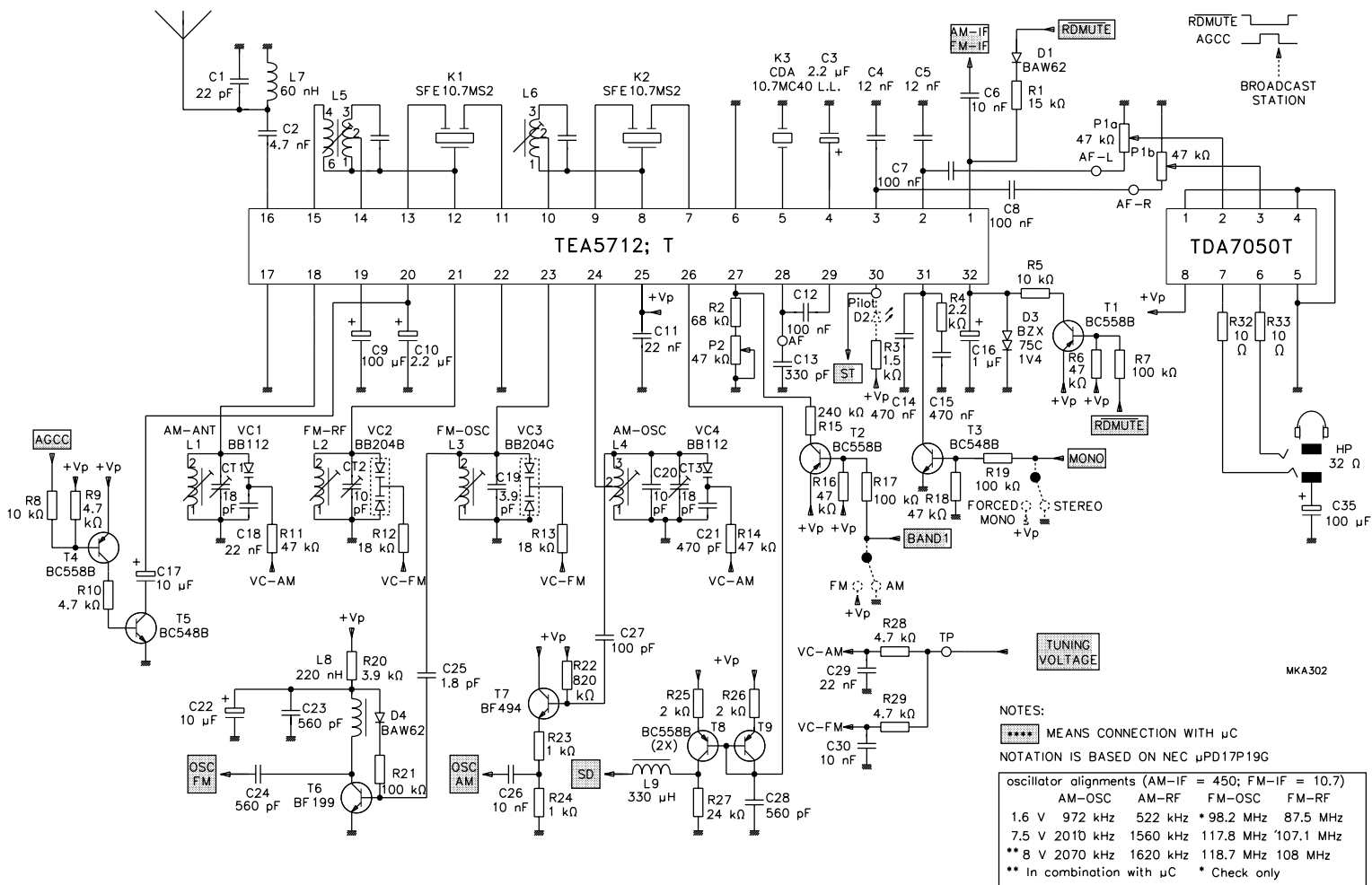


Fig.8 Application circuit of TEA5712 (AM: 522 to 1611 kHz, FM: 87.5 to 108 MHz) with stereo headphone amplifier TDA7050T.

AM/FM stereo DTS radio circuit

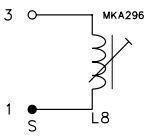
TEA5712; TEA5712T

Components for Fig.8

NUMBER	TYPE	DESCRIPTION	CIRCUIT
<b>Coils</b>			
L1	AM-AERIAL	ferroceptor length = 6 cm L1-2 = 203 $\mu$ H unloaded Q	
L2	FM-RF	L1-2 = 90 nH N1-2 = 2.5 turns unloaded Q = 150T TOKO type S18	
L3	FM-OSC	L1-2 = 70 nH N1-2 = 1.5 turns unloaded Q = 150 TOKO type S18	
L4	AM-OSC	L1-3 = 98 $\mu$ H N1-2 = 12 N2-3 = 39 unloaded Q = 100 wire diameter 0.07 mm TOKO type 7P material TOKO 7BRS	
L5	AM-IF1	L1-3 = 625 $\mu$ H N1-2 = 17 turns N2-3 = 141 turns N4-6 = 10 turns C1-3 = 180 pF unloaded Q = 90 wire diameter 0.07 mm TOKO type 7P material TOKO 7MCS	
L6	AM-IF2	L1-3 = 625 $\mu$ H N1-2 = 28 turns N2-3 = 130 turns C1-3 = 180 pF unloaded Q = 90 wire diameter 0.07 mm TOKO type 7P material TOKO 7MCS	
L7	FM-AERIAL	printcoil L1-2 = 60 nH N1-2 = 2.5 turns	

AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

NUMBER	TYPE	DESCRIPTION	CIRCUIT
L8	AM-RF	test circuit only: L1-3 = 40 $\mu$ H N1-3 = 34 turns unloaded Q = 85 wire diameter 0.09 mm TOKO type 7P material TOKO 7BRS	
<b>Ceramic filters</b>			
K1	FM-IF1	Murata SFE 10.7 MS 2	
K2	FM-IF2	Murata SFE 10.7 MS 2	
K3	FM-DET	Murata CDA 10.7 MC 40	
<b>Variable capacitance diodes</b>			
	FM-RF	BB204B	
	FM-OSC	BB204G	
	FM-RF	BB112	
	AM-OSC	BB112	

Application remarks

- Short circuiting: **all** pins are short-circuit proof except **pin 16** (FM-RF<sub>I</sub>) with respect to the supply voltage pin.
- Align VCO with aerial signal present.

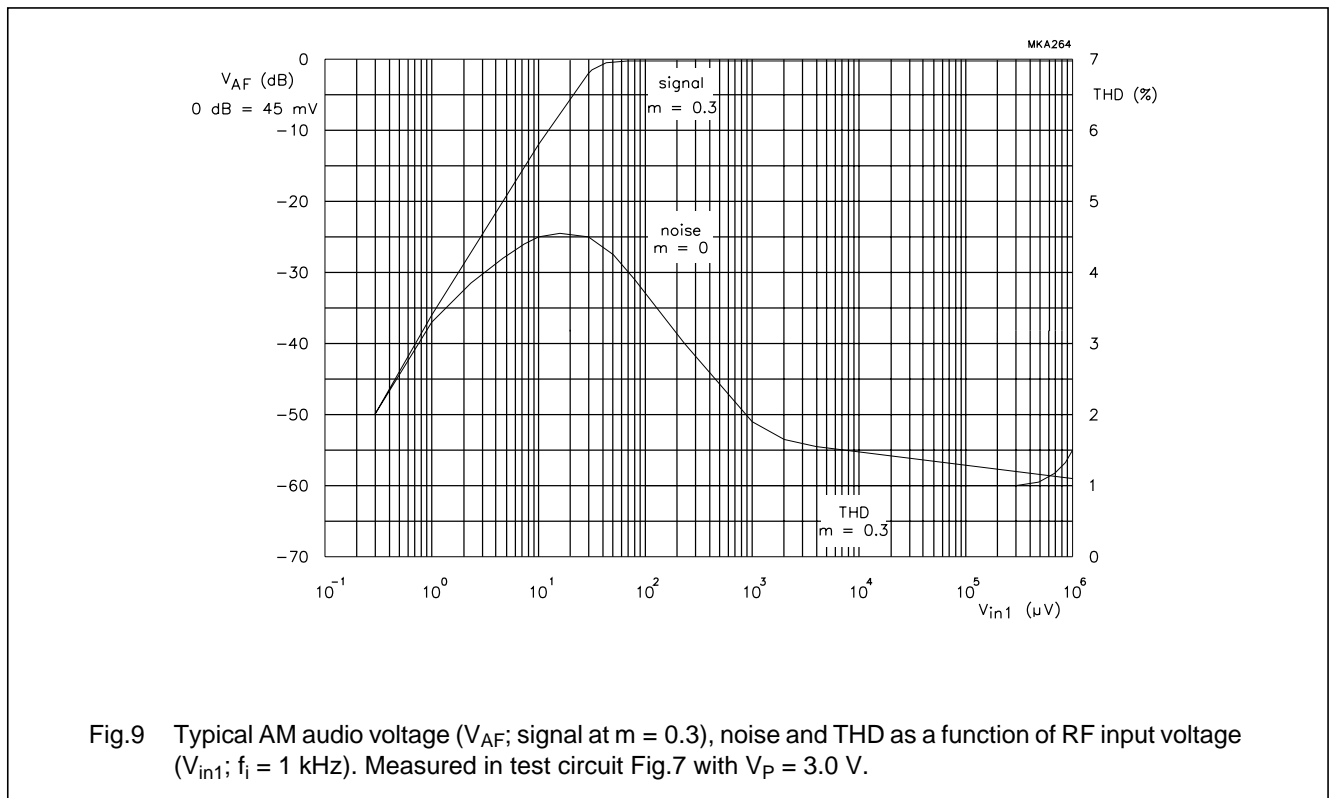


Fig.9 Typical AM audio voltage ( $V_{AF}$ ; signal at  $m = 0.3$ ), noise and THD as a function of RF input voltage ( $V_{in1}$ ;  $f_i = 1$  kHz). Measured in test circuit Fig.7 with  $V_P = 3.0$  V.

AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

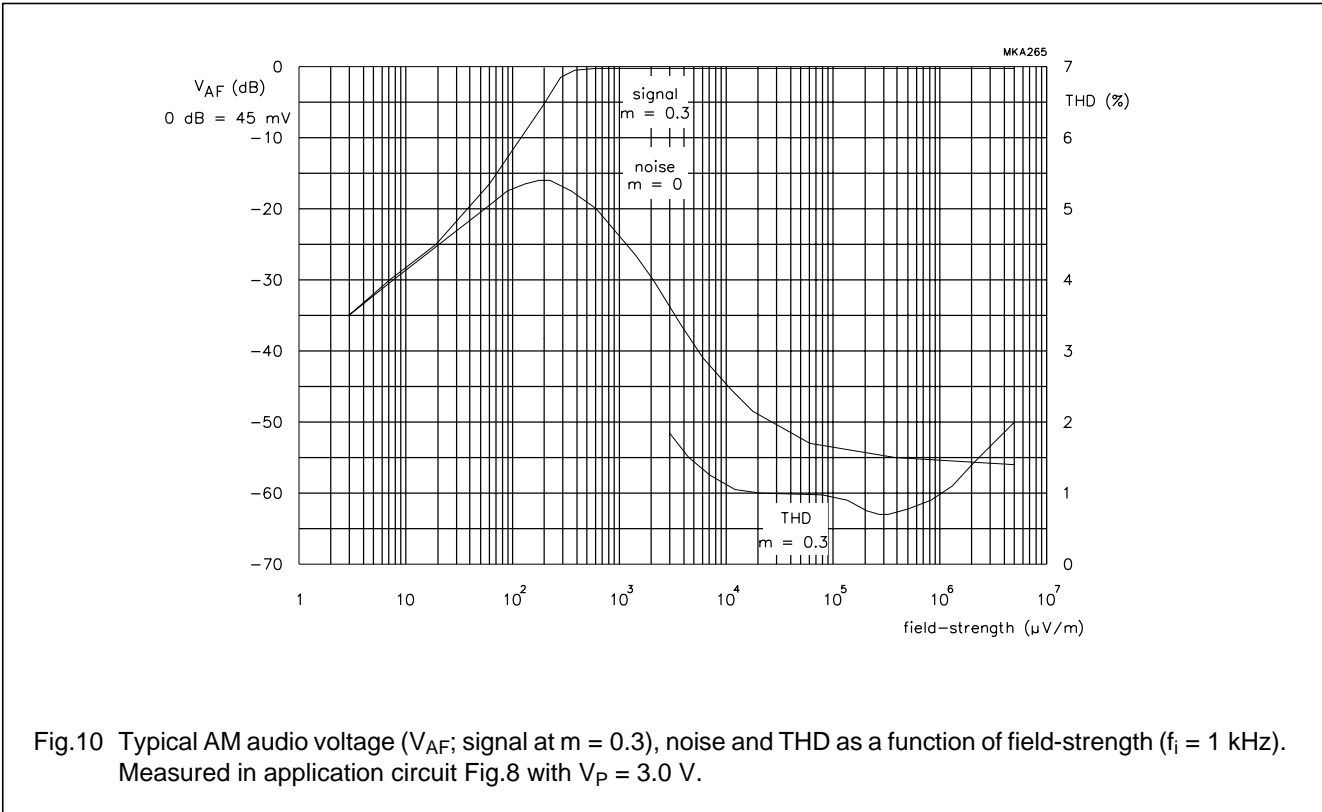


Fig.10 Typical AM audio voltage ( $V_{AF}$ ; signal at  $m = 0.3$ ), noise and THD as a function of field-strength ( $f_i = 1$  kHz). Measured in application circuit Fig.8 with  $V_P = 3.0$  V.

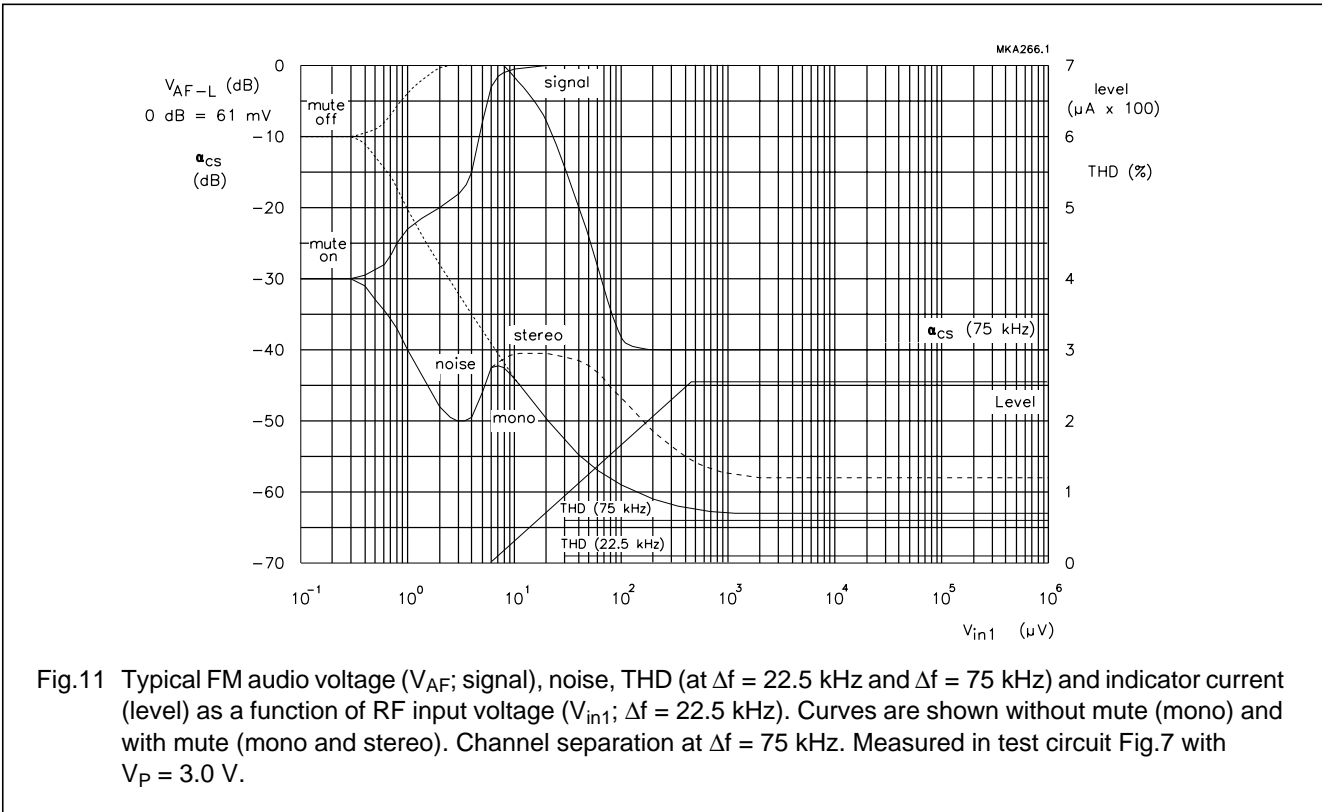
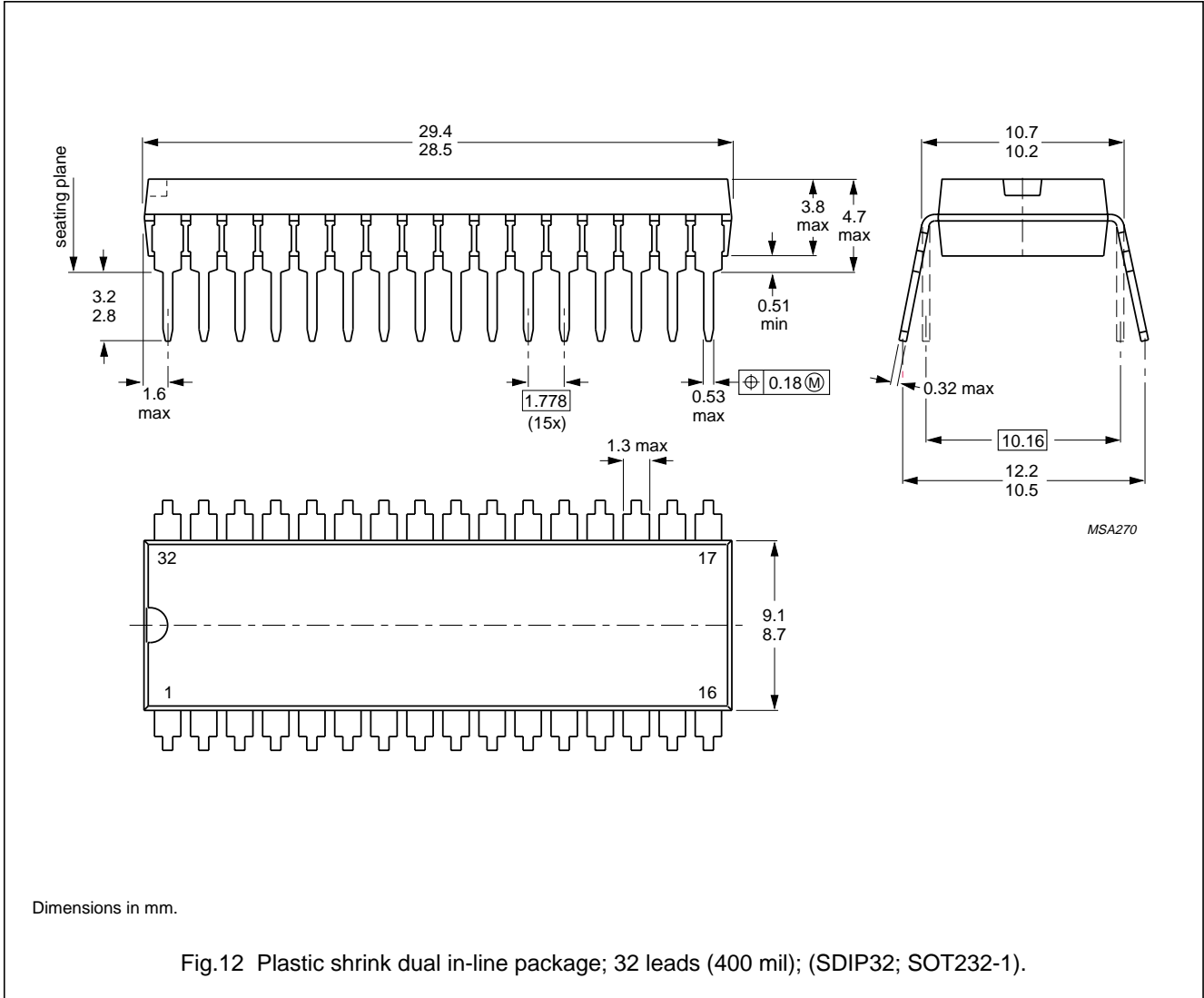


Fig.11 Typical FM audio voltage ( $V_{AF}$ ; signal), noise, THD (at  $\Delta f = 22.5$  kHz and  $\Delta f = 75$  kHz) and indicator current (level) as a function of RF input voltage ( $V_{in1}$ ;  $\Delta f = 22.5$  kHz). Curves are shown without mute (mono) and with mute (mono and stereo). Channel separation at  $\Delta f = 75$  kHz. Measured in test circuit Fig.7 with  $V_P = 3.0$  V.

AM/FM stereo DTS radio circuit

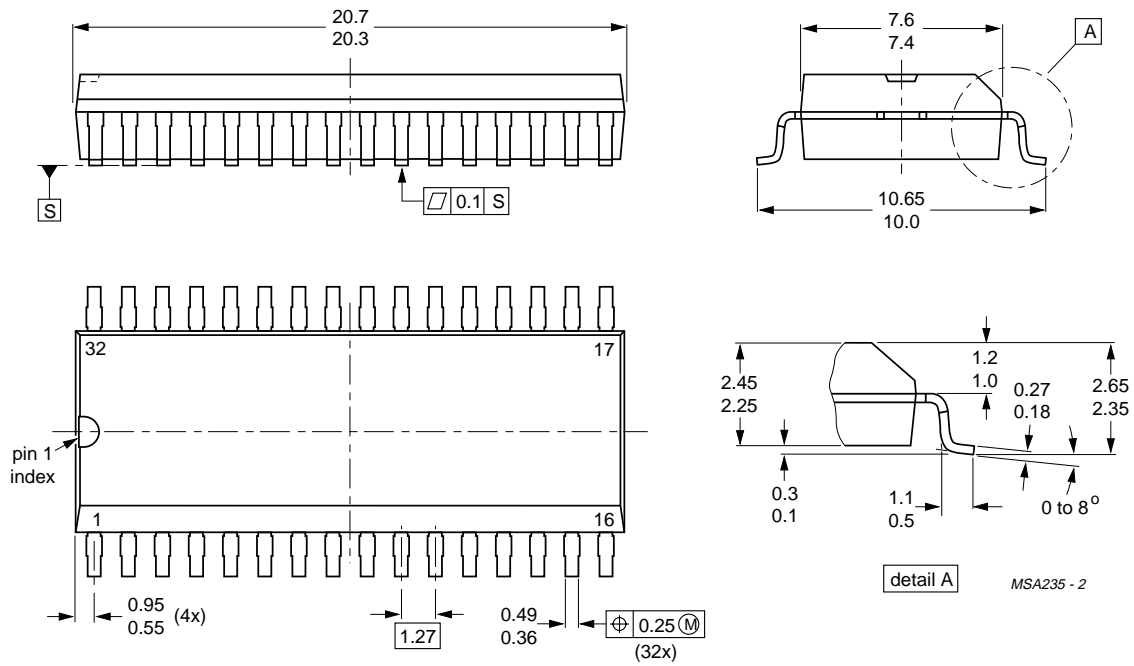
TEA5712; TEA5712T

PACKAGE OUTLINES



AM/FM stereo DTS radio circuit

TEA5712; TEA5712T



Dimensions in mm.

Fig.13 Plastic small outline package; 32 leads; body width 7.5 mm (SO32; SOT287-1).

---

**AM/FM stereo DTS radio circuit****TEA5712; TEA5712T**

---

**SOLDERING****Plastic dual in-line packages**

BY DIP OR WAVE

The maximum permissible temperature of the solder is 260 °C; this temperature must not be in contact with the joint for more than 5 s. The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified storage maximum. If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

**REPAIRING SOLDERED JOINTS**

Apply the soldering iron below the seating plane (or not more than 2 mm above it). If its temperature is below 300 °C, it must not be in contact for more than 10 s; if between 300 and 400 °C, for not more than 5 s.

**Plastic small-outline packages**

BY WAVE

During placement and before soldering, the component must be fixed with a droplet of adhesive. After curing the adhesive, the component can be soldered. The adhesive can be applied by screen printing, pin transfer or syringe dispensing.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder bath is 10 s, if allowed to cool to less than 150 °C within 6 s. Typical dwell time is 4 s at 250 °C.

A modified wave soldering technique is recommended using two solder waves (dual-wave), in which a turbulent wave with high upward pressure is followed by a smooth laminar wave. Using a mildly-activated flux eliminates the need for removal of corrosive residues in most applications.

**BY SOLDER PASTE REFLOW**

Reflow soldering requires the solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the substrate by screen printing, stencilling or pressure-syringe dispensing before device placement.

Several techniques exist for reflowing; for example, thermal conduction by heated belt, infrared, and vapour-phase reflow. Dwell times vary between 50 and 300 s according to method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 min. at 45 °C.

**REPAIRING SOLDERED JOINTS (BY HAND-HELD SOLDERING IRON OR PULSE-HEATED SOLDER TOOL)**

Fix the component by first soldering two, diagonally opposite, end pins. Apply the heating tool to the flat part of the pin only. Contact time must be limited to 10 s at up to 300 °C. When using proper tools, all other pins can be soldered in one operation within 2 to 5 s at between 270 and 320 °C. (Pulse-heated soldering is not recommended for SO packages.)

For pulse-heated solder tool (resistance) soldering of VSO packages, solder is applied to the substrate by dipping or by an extra thick tin/lead plating before package placement.



## AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

**DEFINITIONS**

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

**LIFE SUPPORT APPLICATIONS**

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

---

**NOTES**

AM/FM stereo DTS radio circuit

TEA5712; TEA5712T

---

**NOTES**

## Philips Semiconductors – a worldwide company

**Argentina:** IEROD, Av. Juramento 1992 - 14.b, (1428)  
BUENOS AIRES, Tel. (541)786 7633, Fax. (541)786 9367

**Australia:** 34 Waterloo Road, NORTH RYDE, NSW 2113,  
Tel. (02)805 4455, Fax. (02)805 4466

**Austria:** Triester Str. 64, A-1101 WIEN, P.O. Box 213,  
Tel. (01)60 101-1236, Fax. (01)60 101-1211

**Belgium:** Postbus 90050, 5600 PB EINDHOVEN, The Netherlands,  
Tel. (31)40 783 749, Fax. (31)40 788 399

**Brazil:** Rua do Rocio 220 - 5<sup>th</sup> floor, Suite 51,  
CEP: 04552-903-SÃO PAULO-SP, Brazil.  
P.O. Box 7383 (01064-970).

Tel. (011)821-2333, Fax. (011)829-1849

**Canada:** PHILIPS SEMICONDUCTORS/COMPONENTS:  
Tel. (800) 234-7381, Fax. (708) 296-8556

**Chile:** Av. Santa Maria 0760, SANTIAGO,  
Tel. (02)773 816, Fax. (02)777 6730

**Colombia:** IPRELENZO LTDA, Carrera 21 No. 56-17,  
77621 BOGOTA, Tel. (571)249 7624/(571)217 4609,  
Fax. (571)217 4549

**Denmark:** Prags Boulevard 80, PB 1919, DK-2300 COPENHAGEN S,  
Tel. (032)88 2636, Fax. (031)57 1949

**Finland:** Sinikalliontie 3, FIN-02630 ESPOO,  
Tel. (9)0-50261, Fax. (9)0-520971

**France:** 4 Rue du Port-aux-Vins, BP317,  
92156 SURESNES Cedex,  
Tel. (01)4099 6161, Fax. (01)4099 6427

**Germany:** P.O. Box 10 63 23, 20043 HAMBURG,  
Tel. (040)3296-0, Fax. (040)3296 213.

**Greece:** No. 15, 25th March Street, GR 17778 TAVROS,  
Tel. (01)4894 339/4894 911, Fax. (01)4814 240

**Hong Kong:** PHILIPS HONG KONG Ltd., 6/F Philips Ind. Bldg.,  
24-28 Kung Yip St., KWAI CHUNG, N.T.,  
Tel. (852)424 5121, Fax. (852)428 6729

**India:** Philips INDIA Ltd, Shivsagar Estate, A Block,  
Dr. Annie Besant Rd. Worli, Bombay 400 018  
Tel. (022)4938 541, Fax. (022)4938 722

**Indonesia:** Philips House, Jalan H.R. Rasuna Said Kav. 3-4,  
P.O. Box 4252, JAKARTA 12950,  
Tel. (021)5201 122, Fax. (021)5205 189

**Ireland:** Newstead, Clonskeagh, DUBLIN 14,  
Tel. (01)640 000, Fax. (01)640 200

**Italy:** PHILIPS SEMICONDUCTORS S.r.l.,  
Piazza IV Novembre 3, 20124 MILANO,  
Tel. (0039)2 6752 2531, Fax. (0039)2 6752 2557

**Japan:** Philips Bldg 13-37, Kohnan2-chome, Minato-ku, TOKYO 108,  
Tel. (03)3740 5028, Fax. (03)3740 0580

**Korea:** (Republic of) Philips House, 260-199 Itaewon-dong,  
Yongsan-ku, SEOUL, Tel. (02)794-5011, Fax. (02)798-8022

**Malaysia:** No. 76 Jalan Universiti, 46200 PETALING JAYA,  
SELANGOR, Tel. (03)750 5214, Fax. (03)757 4880

**Mexico:** 5900 Gateway East, Suite 200, EL PASO, TX 79905,  
Tel. 9-5(800)234-7381, Fax. (708)296-8556

**Netherlands:** Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB  
Tel. (040)783749, Fax. (040)788399

**New Zealand:** 2 Wagener Place, C.P.O. Box 1041, AUCKLAND,  
Tel. (09)849-4160, Fax. (09)849-7811

**Norway:** Box 1, Manglerud 0612, OSLO,  
Tel. (022)74 8000, Fax. (022)74 8341

**Pakistan:** Philips Electrical Industries of Pakistan Ltd.,  
Exchange Bldg. ST-2/A, Block 9, KDA Scheme 5, Clifton,  
KARACHI 75600, Tel. (021)587 4641-49,  
Fax. (021)577035/5874546.

**Philippines:** PHILIPS SEMICONDUCTORS PHILIPPINES Inc,  
196 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI,  
Metro MANILA, Tel. (02)810 0161, Fax. (02)817 3474

**Portugal:** PHILIPS PORTUGUESA, S.A.,  
Rua dr. António Loureiro Borges 5, Arquiparque - Miraflores,  
Apartado 300, 2795 LINDA-A-VELHA,  
Tel. (01)4163160/4163333, Fax. (01)4163174/4163366.

**Singapore:** Lorong 1, Toa Payoh, SINGAPORE 1231,  
Tel. (65)350 2000, Fax. (65)251 6500

**South Africa:** S.A. PHILIPS Pty Ltd.,  
195-215 Main Road Martindale, 2092 JOHANNESBURG,  
P.O. Box 7430 Johannesburg 2000,  
Tel. (011)470-5911, Fax. (011)470-5494.

**Spain:** Balmes 22, 08007 BARCELONA,  
Tel. (03)301 6312, Fax. (03)301 42 43

**Sweden:** Kottbygatan 7, Akalla. S-164 85 STOCKHOLM,  
Tel. (0)8-632 2000, Fax. (0)8-632 2745

**Switzerland:** Allmendstrasse 140, CH-8027 ZÜRICH,  
Tel. (01)488 2211, Fax. (01)481 77 30

**Taiwan:** PHILIPS TAIWAN Ltd., 23-30F, 66, Chung Hsiao West  
Road, Sec. 1, Taipei, Taiwan ROC, P.O. Box 22978,  
TAIPEI 100, Tel. (02)388 7666, Fax. (02)382 4382.

**Thailand:** PHILIPS ELECTRONICS (THAILAND) Ltd.,  
209/2 Sanpavuth-Bangna Road Prakanong,  
Bangkok 10260, THAILAND,  
Tel. (662)398-0141, Fax. (662)398-3319.

**Turkey:** Talatpasa Cad. No. 5, 80640 GÜLTEPE/ISTANBUL,  
Tel. (0212)279 2770, Fax. (0212)269 3094

**United Kingdom:** Philips Semiconductors LTD.,  
276 Bath road, Hayes, MIDDLESEX UB3 5BX,  
Tel. (081)73050000, Fax. (081)7548421

**United States:** 811 East Arques Avenue, SUNNYVALE,  
CA 94088-3409, Tel. (800)234-7381, Fax. (708)296-8556

**Uruguay:** Coronel Mora 433, MONTEVIDEO,  
Tel. (02)70-4044, Fax. (02)92 0601

**For all other countries apply to:** Philips Semiconductors,  
International Marketing and Sales, Building BE-p,  
P.O. Box 218, 5600 MD, EINDHOVEN, The Netherlands,  
Telex 35000 phtcnl, Fax. +31-40-724825

SCD35 © Philips Electronics N.V. 1994

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

# Philips Semiconductors



# PHILIPS